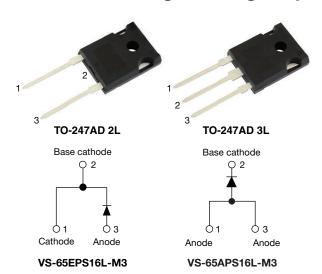


Vishay Semiconductors

COMPLIANT

HALOGEN FREE

# High Voltage Input Rectifier Diode, 65 A



PRIMARY CHARACTERISTICS					
I <sub>F(AV)</sub> 65 A					
$V_{R}$	1600 V				
V <sub>F</sub> at I <sub>F</sub>	1.17 V				
I <sub>FSM</sub>	950 A				
T <sub>J</sub> max.	150 °C				
Package	TO-247AD 2L, TO-247AD 3L				
Circuit configuration	Single				

### **FEATURES**

- · Very low forward voltage drop
- · Glass passivated pellet chip junction
- Designed and qualified according to JEDEC® - JESD 47
- Flexible solution for reliable AC power rectification
- High surge, low V<sub>F</sub> rugged blocking diode for DC charging stations
- AEC-Q101 qualified P/N available (VS-65EPS16LHM3, VS-65APS16LHM3)
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912"><u>www.vishay.com/doc?99912</u></a>

#### **APPLICATIONS**

- On-board and off-board EV / HEV battery chargers
- Renewable energy inverters
- Input rectification for single and three phase bridge configurations
- Vishay Semiconductors switches and output rectifiers which are available in identical package outlines

### **DESCRIPTION**

High voltage rectifiers optimized for very low forward voltage drop with moderate leakage.

These devices are intended for use in main rectification (single or three phase bridge).

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	VALUES	UNITS		
I <sub>F(AV)</sub>	Sinusoidal waveform	65	A		
V <sub>RRM</sub>		1600	V		
I <sub>FSM</sub>		950	Α		
V <sub>F</sub>	30 A, T <sub>J</sub> = 25 °C	1.0	V		
TJ		-40 to +150	°C		

VOLTAGE RATINGS						
PART NUMBER  V <sub>RRM</sub> , MAXIMUM PEAK REVERSE VOLTAGE V		V <sub>RSM</sub> , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I <sub>RRM</sub> AT 150 °C mA			
VS-65EPS16L-M3	1600	1700	1.3			
VS-65APS16L-M3	1600	1700	1.3			

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum average forward current	I <sub>F(AV)</sub>	$T_C = 120$ °C, 180° conduction half sine wave	65		
Maximum peak one cycle	I <sub>FSM</sub>	10 ms sine pulse, rated V <sub>RRM</sub> applied	800	Α	
non-repetitive surge current		10 ms sine pulse, no voltage reapplied	950		
Maximum I <sup>2</sup> t for fusing	I <sup>2</sup> t	10 ms sine pulse, rated V <sub>RRM</sub> applied		A <sup>2</sup> s	
Maximum I-t for fusing	1-1	10 ms sine pulse, no voltage reapplied 4510			
Maximum I <sup>2</sup> √t for fusing	I <sup>2</sup> √t	t = 0.1 ms to 10 ms, no voltage reapplied	45 100	A <sup>2</sup> √s	

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ELECTRICAL SPECIFICATIONS						
PARAMETER	IDITIONS	VALUES	UNITS			
Maximum forward voltage drop	$V_{FM}$	65 A, T <sub>J</sub> = 25 °C		1.17	V	
Forward slope resistance	r <sub>t</sub>	T <sub>J</sub> = 150 °C		3.98	mΩ	
Threshold voltage	V <sub>F(TO)</sub>			0.74	V	
Maximum rayarra laakaga gurrant		$V_{\rm R}$ = rated $V_{\rm RRM}$	0.1	mA		
Maximum reverse leakage current	IRM	T <sub>J</sub> = 150 °C	v <sub>R</sub> = rateu v <sub>RRM</sub>	1.3	IIIA I	

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and storage temper	ature range	T <sub>J</sub> , T <sub>Stg</sub>		-40 to +150	°C	
Maximum thermal resistance, junction	to case	$R_{thJC}$	DC operation	0.25		
Maximum thermal resistance, junction to ambient		$R_{thJA}$		40	°C/W	
Typical thermal resistance, case to heatsink		R <sub>thCS</sub>	Mounting surface, smooth, and greased	0.25		
Approximate weight				6	g	
Approximate weight				0.21	oz.	
Mounting torque	minimum			6 (5)	kgf ⋅ cm	
Mounting torque	maximum			12 (10)	(lbf · in)	
Maddin date			Case style TO-247AD 2L	65EP	S16L	
Marking device			Case style TO-247AD 3L	65AF	S16L	

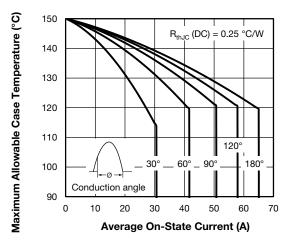


Fig. 1 - Current Rating Characteristics

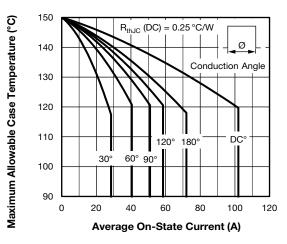


Fig. 2 - Current Rating Characteristics



## Vishay Semiconductors

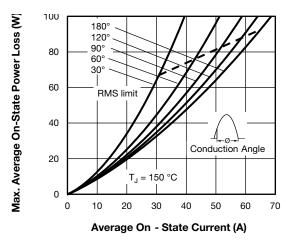


Fig. 3 - Forward Power Loss Characteristics

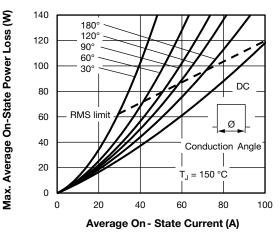


Fig. 4 - Forward Power Loss Characteristics

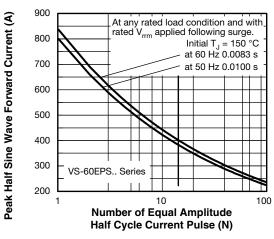


Fig. 5 - Maximum Non-Repetitive Surge Current

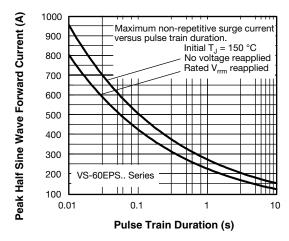


Fig. 6 - Maximum Non-Repetitive Surge Current

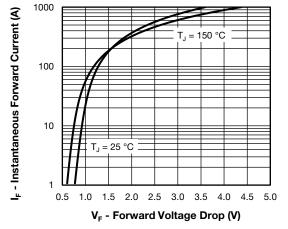


Fig. 7 - Forward Voltage Drop Characteristics

### Vishay Semiconductors

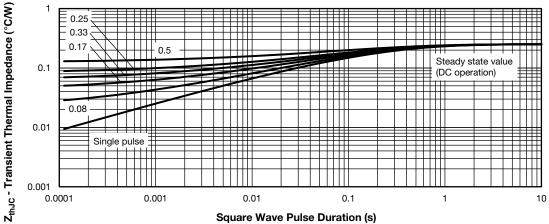
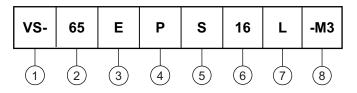


Fig. 8 - Thermal Impedance Z<sub>thJC</sub> Characteristics

### **ORDERING INFORMATION TABLE**

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Vishay Semiconductors product

2 - Current rating (65 = 65 A)

3 - Circuit configuration:

E = single, 2 pins

A = single, 3 pins

4 - Package:

P = TO-247AD

5 - Type of silicon:

S = standard recovery rectifier

6 - Voltage code x 100 = V<sub>RRM</sub> — 16 = 1600 V

7 - L = long leads

8 - Environmental digit:

-M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

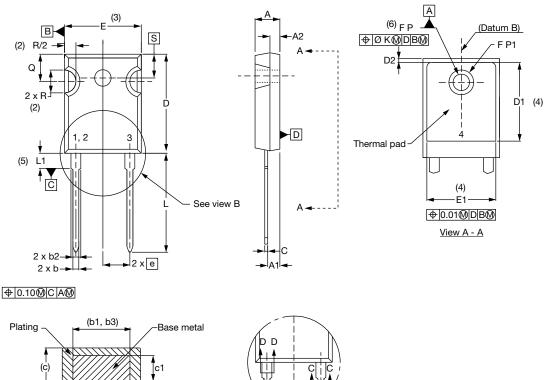
ORDERING INFORMATION (Example)					
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION		
VS-65EPS16L-M3	25	500	Antistatic plastic tubes		
VS-65APS16L-M3	25	500	Antistatic plastic tubes		

LINKS TO RELATED DOCUMENTS					
Dimensions TO-247AD 2L <u>www.vishay.com/doc?95536</u>					
Differisions	TO-247AD 3L	www.vishay.com/doc?95626			
Port marking information	TO-247AD 2L	www.vishay.com/doc?95648			
Part marking information	TO-247AD 3L	www.vishay.com/doc?95007			

## Vishay Semiconductors

### **TO-247AD 2L**

### **DIMENSIONS** in millimeters and inches



D D C C
<u>View B</u>

SYMBOL	MILLIN	IETERS	INCHES		NOTES
STIVIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.65	5.31	0.183	0.209	
A1	2.21	2.59	0.087	0.102	
A2	1.50	2.49	0.059	0.098	
b	0.99	1.40	0.039	0.055	
b1	0.99	1.35	0.039	0.053	
b2	1.65	2.39	0.065	0.094	
b3	1.65	2.34	0.065	0.092	
С	0.38	0.89	0.015	0.035	
c1	0.38	0.84	0.015	0.033	
D	19.71	20.70	0.776	0.815	3
D1	13.08	-	0.515	-	4
D2	0.51	1.35	0.020	0.053	

SYMBOL	MILLIMETERS		INCHES		NOTES
	MIN.	MAX.	MIN.	MAX.	NOTES
Е	15.29	15.87	0.602	0.625	3
E1	13.46	-	0.53	-	
е	5.46 BSC		0.215 BSC		
ØK	0.254		0.010		
L	19.81	20.32	0.780	0.800	
L1	3.71	4.29	0.146	0.169	
ØΡ	3.56	3.66	0.14	0.144	
Ø P1	-	6.98	-	0.275	
Q	5.31	5.69	0.209	0.224	
R	4.52	5.49	0.178	0.216	
S	5.51 BSC		0.217 BSC		

#### **Notes**

- (1) Dimensioning and tolerancing per ASME Y14.5M-1994
- (2) Contour of slot optional
- (3) Dimension D and E do not include mold flash. These dimensions are measured at the outermost extremes of the plastic body
- (4) Thermal pad contour optional with dimensions D1 and E1
- Lead finish uncontrolled in L1
- (6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- (7) Outline conforms to JEDEC® outline TO-247 with exception of dimension A min., D, E min., Q min., S, and note 4



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